



# DDTA (R2-ONLY SERIES) KA

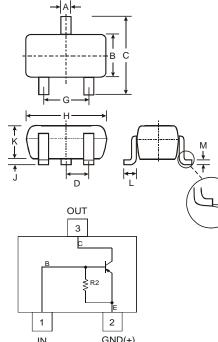
PNP PRE-BIASED SMALL SIGNAL SURFACE MOUNT TRANSISTOR

### **Features**

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistor, R2 only
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device Note 3 & 4

### **Mechanical Data**

- Case: SC-59
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Terminal Connections: See Diagram
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



SC-59								
Dim	Min	Max						
Α	0.35	0.50						
В	1.50	1.70						
С	2.70 3.00							
D	0.95							
G	1.90							
н	2.90 3.10							
J	0.013 0.10							
К	1.00 1.30							
L	0.35	0.55						
М	0.10	0.20						
α	0°	8°						
All Dir	nensions	s in mm						

P/N	R2 (NOM)	Type Code
DDTA114GKA	10KΩ	P26
DDTA124GKA	<b>22K</b> Ω	P27
DDTA144GKA	47ΚΩ	P28
DDTA115GKA	100KΩ	P29



### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	I <sub>C</sub> (Max)	-100	mA
Power Dissipation	Pd	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>0</sub> JA	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	٥C

Notes: 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

 Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



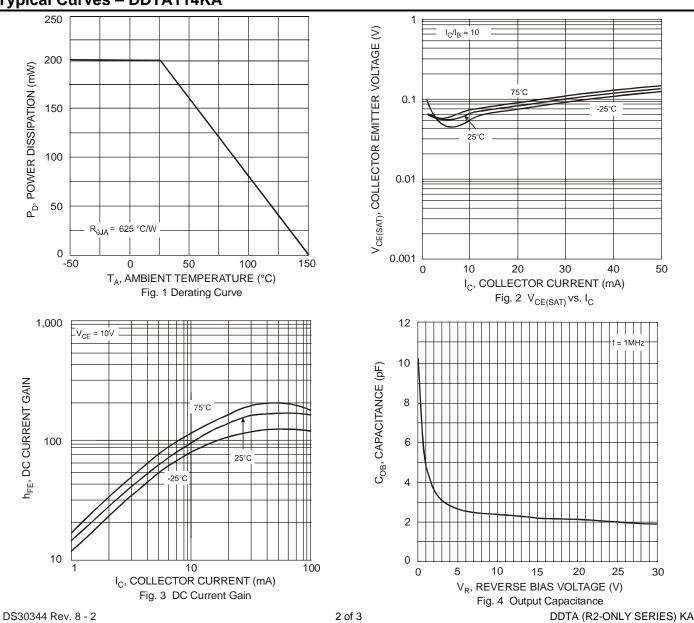
### Electrical Characteristics @T<sub>A</sub> = 25°C unles

 $@T_A = 25^{\circ}C$  unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50			V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Vo			$I_{\rm C} = -1  {\rm mA}$				
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	5	_	_	V	I <sub>E</sub> = -720μA, DDTA114GKA I <sub>E</sub> = -330μA, DDTA124GKA I <sub>E</sub> = -160μA, DDTA144GKA I <sub>E</sub> = -72μA, DDTA115GKA
Collector Cutoff Current		I <sub>CBO</sub>	_	_	-0.5	μΑ	V <sub>CB</sub> = -50V
Emitter Cutoff Current	DDTA114GKA DDTA124GKA DDTA144GKA DDTA115GKA	I <sub>EBO</sub>	-300 -140 -65 -30	_	-580 -260 -130 -58	μA	$V_{EB} = -4V$
Collector-Emitter Saturation Volt	/oltage V <sub>CE(sat)</sub> —0.3 V I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA		$I_{\rm C}$ = -10mA, $I_{\rm B}$ = -0.5mA				
DC Current Transfer Ratio	DDTA114GKA DDTA124GKA DDTA144GKA DDTA115GKA	h <sub>FE</sub>	30 56 68 82	_			I <sub>C</sub> = -5mA, V <sub>CE</sub> = -5V
Bleeder Resistor (R <sub>2</sub> ) Tolerance	÷	$\Delta R_2$	-30		+30	%	—
Gain-Bandwidth Product*		f <sub>T</sub>		250		MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

\* Transistor - For Reference Only

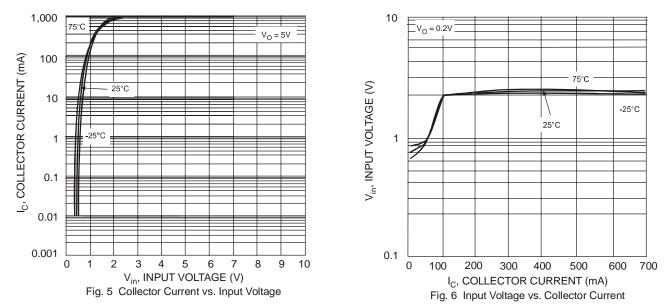
### Typical Curves – DDTA114KA



www.diodes.com

© Diodes Incorporated



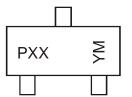


#### Ordering Information (Note 4 & 5)

Device	Packaging	Shipping
DDTA114GKA-7-F	SC-59	3000/Tape & Reel
DDTA124GKA-7-F	SC-59	3000/Tape & Reel
DDTA144GKA-7-F	SC-59	3000/Tape & Reel
DDTA115GKA-7-F	SC-59	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

### **Marking Information**



PXX = Product Type Marking Code, See Table on Page 1 YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	200	6 20	07	2008	2009	1	2010	2011	2012
Code	Ν	Р	R	S	Т	ι	J	V	W		Х	Y	Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Ju	l Au	g Se	эp	Oct	Nov	Dec
Code		0	0	4	-	6	7	0		`	0	NI	D

#### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - Pre-Biased category:

Click to view products by Diodes Incorporated manufacturer:

Other Similar products are found below :

MMUN2217LT1G FP101-TL-E RN1607(TE85L,F) DRC9A14E0L DTA124GKAT146 DTA144WETL DTA144WKAT146 DTC113EET1G DTC115TETL DTC115TKAT146 DTC124TETL DTC144ECA-TP DTC144VUAT106 MUN5241T1G BCR158WH6327XTSA1 NSBA114TDP6T5G NSBA143TF3T5G NSBA143ZF3T5G NSBC114EF3T5G NSBC114YF3T5G NSBC123TF3T5G NSBC143TF3T5G NSVMUN2212T1G NSVMUN5111DW1T3G NSVMUN5314DW1T3G NSVUMC2NT1G SMMUN2134LT1G SMUN2212T1G SMUN5235T1G SMUN5330DW1T1G SSVMUN5312DW1T2G 2SC3650-TD-E RN1303(TE85L,F) RN4605(TE85L,F) BCR135SH6327XT TTEPROTOTYPE79 UMC3NTR DTA113EET1G EMA2T2R EMH15T2R SDTA114YET1G SMMUN2111LT3G SMMUN2113LT1G SMMUN2114LT1G SMMUN2211LT3G SMUN2214T3G SMUN5113DW1T1G SMMUN5335DW1T1G NSBA114YF3T5G NSBC114TF3T5G